



SSL24F-PJ~SSL26F-PJ

Schottky Barrier Diode

Features

- Low power loss, high efficiency
- For surface mounted applications
- High forward surge current capability

SMAF



1.Cathode ————— 2.Anode

Marking Code:
SSL24F-PJ :SSL24
SSL26F-PJ :SSL26

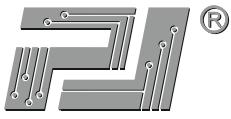
Absolute Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

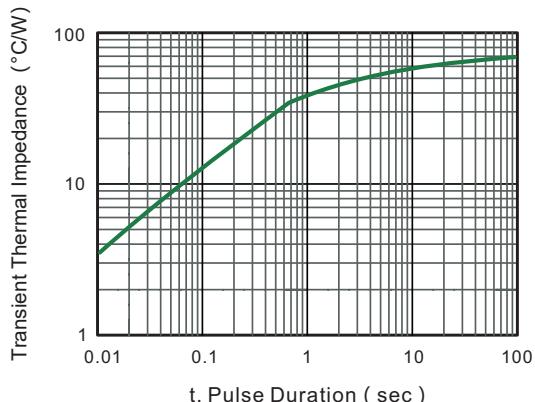
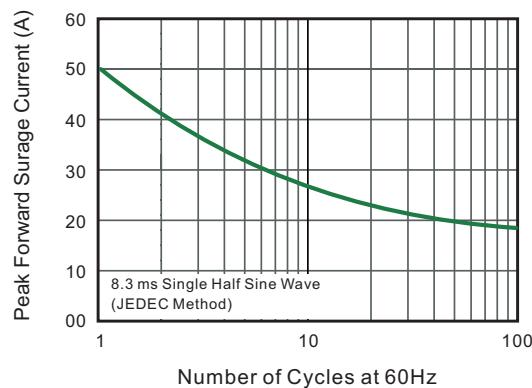
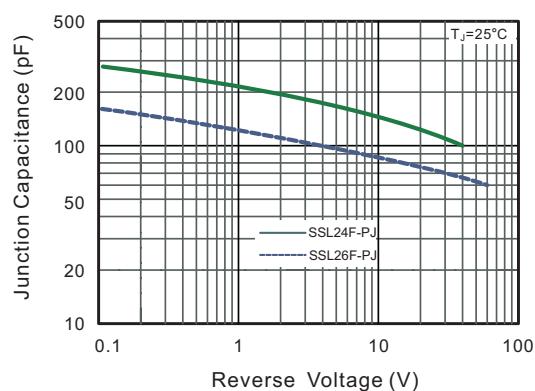
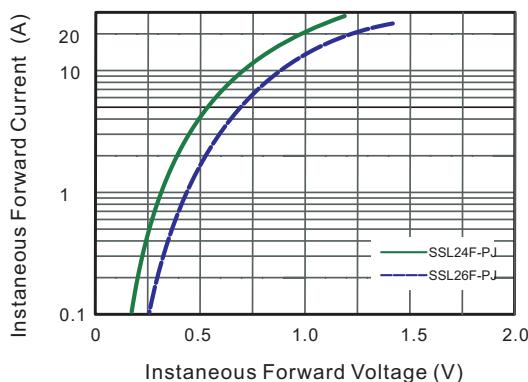
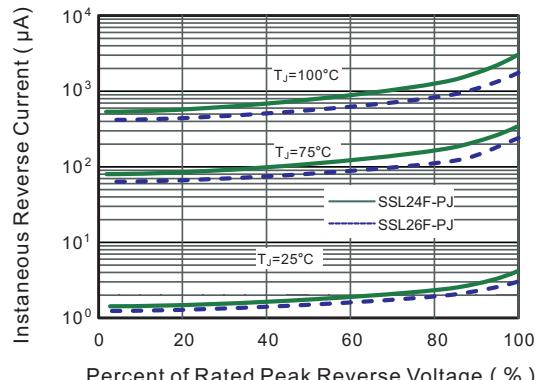
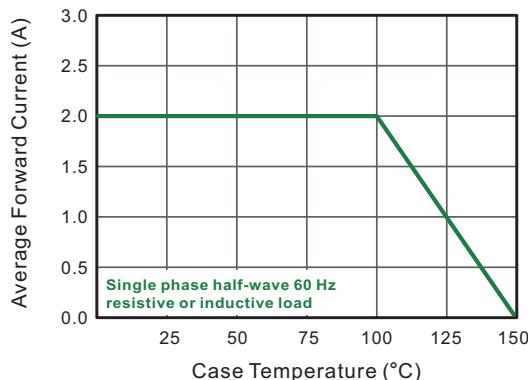
Parameter	Symbol	SSL24F-PJ	SSL26F-PJ	Unit
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	40	60	V
Maximum RMS Voltage	V _{RMS}	28	42	V
Maximum DC Blocking Voltage	V _{DC}	40	60	V
Maximum Average Forward Rectified Current at T _c = 100 °C	I _{F(AV)}	2		A
Peak Forward Surge Current,8.3ms Single Half Sine-wave Superimposed on Rated Load	I _{FSM}	50		A
Maximum Instantaneous Forward Voltage at 2 A	V _F	0.45	0.52	V
Maximum DC Reverse Current at Rated DC Blocking Voltage	I _R	0.5 10	0.3 5	mA
Typical Junction Capacitance ^{Note1}	C _J	290	130	pF
Typical Thermal Resistance ^{Note2}	R _{θJA}	70		°C/W
Operating Junction Temperature Range	T _J	-55 to +150		°C
Storage Temperature Range	T _{STG}	-55 to +150		°C

Note:

1. Measured at 1 MHz and applied reverse voltage of 4 V D.C
2. P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.



Typical Characteristic Curves

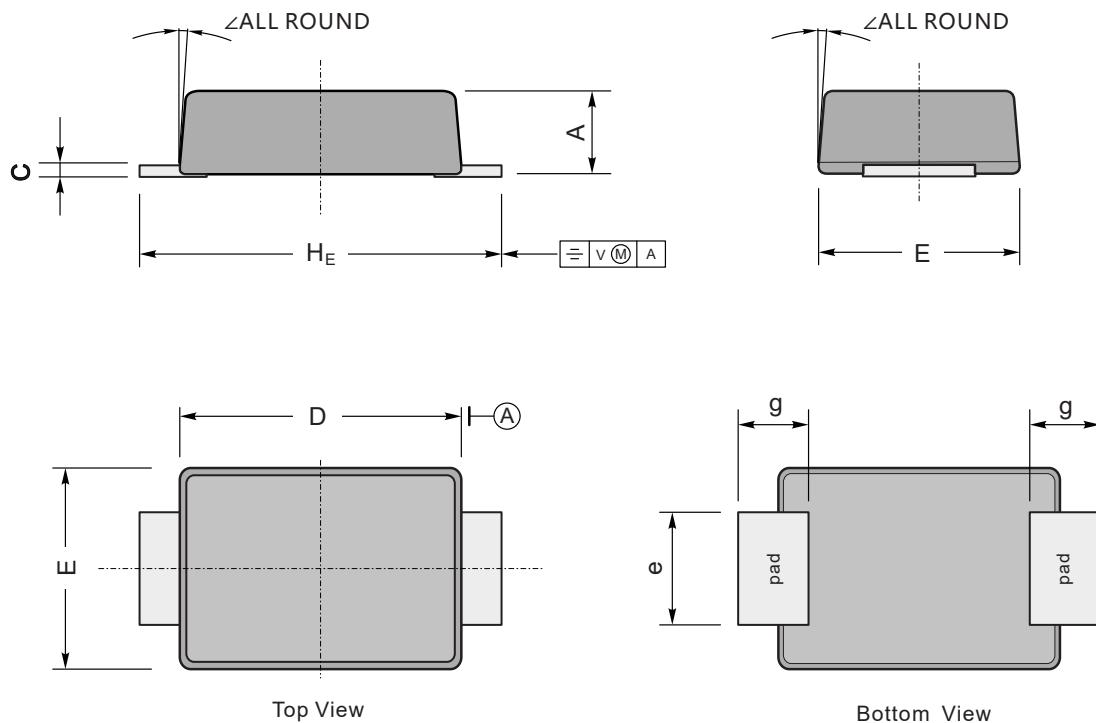




Package Outline

SMAF

Dimensions in mm



UNIT		A	C	D	E	e	g	H _E	∠
mm	max	1.2	0.20	3.7	2.7	1.6	1.2	4.9	7°
	min	0.9	0.12	3.3	2.4	1.3	0.8	4.4	
mil	max	47	7.9	146	106	63	47	193	7°
	min	35	4.7	130	94	51	31	173	